

14th RD50 Workshop

Thursday 4 June 2009

Full detector systems (08:45 - 12:35)

time	[id] title	presenter
08:45	[41] Electrical characteristics of ATLAS07 Series I large detectors.	MIKESTIKOVA, Marcela
09:05	[42] Irradiation program in Prague - status.	KODYS, Peter Dr KODYS, Peter
09:25	[6] Comparison of the CCE properties of microstrip detectors made with different substrates and irradiated with protons and neutrons at different temperature	ANTHONY, Affolder
09:45	[8] Annealing of Charge Collection in Strip sensors and the Depletion Voltage	SADROZINSKI, Hartmut
10:05	[40] Neutron irradiation for p-type sensors. Detector characterization with ALIBAVA system	SOLDEVILA, Urmila
10:25	Coffee break	
10:55	[12] The avalanche effect in operation of heavily irradiated silicon p-i-n detectors	EREMIN, Vladimir
11:15	[7] Can we claim multiplication effects in irradiated silicon?	CASSE, Gianluigi
11:35	[10] Measurements of lorentzangle in highly irradiated silicon-strip-detectors	SCHNEIDER, Michael
11:55	[22] Performance of irradiated MCz detectors in a test beam environment	MAEENPAEAE, Teppo
12:15	[3] Commissioning the CMS pixel detector with cosmic ray data	Prof. CHIOCHIA, Vincenzo